DEPARTMENT OF ELECTRICAL ENGINEERING

T_P]

Source

Gate

P-body

MOX

P⁻layer

BOX

Substrate

Gate oxide

Drain

T_P-layer

T_{pext}

Silicon On Insulator Laboratory

Main Research

- i-TFET CMOS devices application
- **Unipolar CMOS devices application**
- Punch Through CMOS devices application
- **Capacitorless 1T DRAM**
- **High Efficiency Solar cell**

Highlight

Design novel CMOS devices for 5G or 6G technology application.

